National *Semiconductor*

100328

Low Power Octal ECL/TTL Bi-Directional Translator with Latch

General Description

The 100328 is an octal latched bi-directional translator designed to convert TTL logic levels to 100K ECL logic levels and vice versa. The direction of this translation is determined by the DIR input. A LOW on the output enable input (OE) holds the ECL outputs in a cut-off state and the TTL outputs at a high impedance level. A HIGH on the latch enable input (LE) latches the data at both inputs even though only one output is enabled at the time. A LOW on LE makes the 100328 transparent.

The cut-off state is designed to be more negative than a normal ECL LOW level. This allows the output emitter-followers to turn off when the termination supply is –2.0V, presenting a high impedance to the data bus. This high impedance reduces termination power and prevents loss of low state noise margin when several loads share the bus.

The 100328 is designed with FAST® TTL output buffers, featuring optimal DC drive and capable of quickly charging and discharging highly capacitive loads. All inputs have 50 kΩ pull-down resistors.

Features

- Identical performance to the 100128 at 50% of the supply current
- Bi-directional translation
- 2000V ESD protection
- Latched outputs
- FAST TTL outputs
- TRI-STATE® outputs
- Voltage compensated operating range = –4.2V to –5.7V
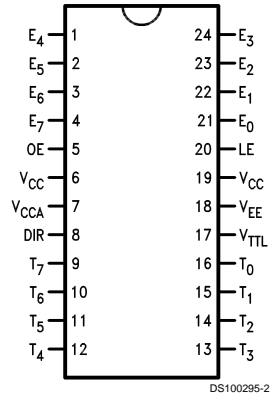- Available to MIL-STD-883

Logic Symbol

DS100295-1
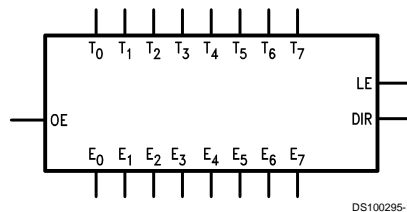
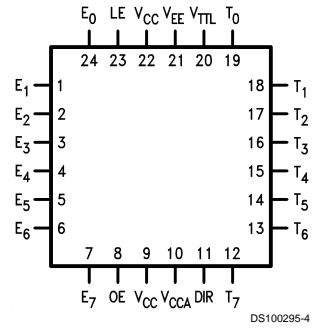| Pin Names	Description
E_0–E_7	ECL Data I/O
T_0–T_7	TTL Data I/O
OE	Output Enable Input
LE	Latch Enable Input
DIR	Direction Control Input

All pins function at 100K ECL levels except for T_0–T_7.

Connection Diagrams

24-Pin DIP

E_4	1	24	E_3
E_5	2	23	E_2
E_6	3	22	E_1
E_7	4	21	E_0
OE	5	20	LE
V_{CC}	6	19	V_{CC}
V_{CCA}	7	18	V_{EE}
DIR	8	17	V_{TTL}
T_7	9	16	T_0
T_6	10	15	T_1
T_5	11	14	T_2
T_4	12	13	T_3

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24-Pin Quad Cerpak

Top pins (left to right): E_0 (24), LE (23), V_{CC} (22), V_{EE} (21), V_{TTL} (20), T_0 (19)

Left pins (top to bottom): E_1 (1), E_2 (2), E_3 (3), E_4 (4), E_5 (5), E_6 (6)

Right pins (top to bottom): T_1 (18), T_2 (17), T_3 (16), T_4 (15), T_5 (14), T_6 (13)

Bottom pins (left to right): E_7 (7), OE (8), V_{CC} (9), V_{CCA} (10), DIR (11), T_7 (12)

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Functional Diagram

SEE DETAIL

ECL 0 — TTL 0
ECL 1 — TTL 1
ECL 2 — TTL 2
ECL 3 — TTL 3
ECL 4 — TTL 4
ECL 5 — TTL 5
ECL 6 — TTL 6
ECL 7 — TTL 7

(LE) LATCH ENABLE

(DIR) ECL/TTL — DECODE
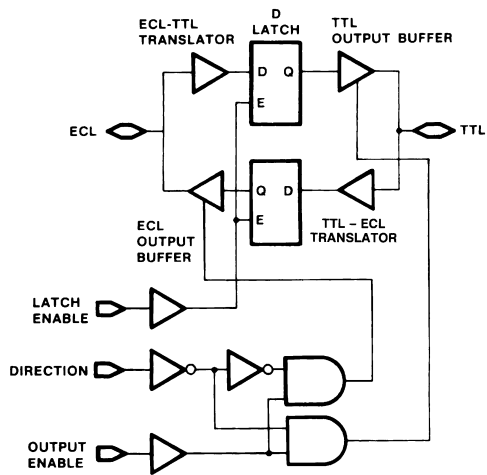(OE) OUTPUT ENABLE

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Note: LE, DIR, and OE use ECL logic levels

Detail

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Truth Table

OE	DIR	LE	ECL Port	TTL Port	Notes
L	X	L	LOW (Cut-Off)	Z	
L	L	H	Input	Z	(Notes 1, 3)
L	H	H	LOW (Cut-Off)	Input	(Notes 2, 3)
H	L	L	L	L	(Notes 1, 4)
H	L	L	H	H	(Notes 1, 4)
H	L	H	X	Latched	(Notes 1, 3)
H	H	L	L	L	(Notes 2, 4)
H	H	L	H	H	(Notes 2, 4)
H	H	H	Latched	X	(Notes 2, 4)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High Impedance

Note 1: ECL input to TTL output mode.

Note 2: TTL input to ECL output mode.

Note 3: Retains data present before LE set HIGH.

Note 4: Latch is transparent.

Absolute Maximum Ratings (Note 5)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature (T_{STG})	–65˚C to +150˚C
Maximum Junction Temperature (T_J)	
Ceramic	+175˚C
V_{EE} Pin Potential to	
Ground Pin	–7.0V to +0.5V
V_{TTL} Pin Potential to	
Ground Pin	–0.5V to +6.0V
ECL Input Voltage (DC)	V_{EE} to +0.5V
ECL Output Current	
(DC Output HIGH)	–50 mA
TTL Input Voltage (Note 7)	–0.5V to +6.0V
TTL Input Current (Note 7)	–30 mA to +5.0 mA

Voltage Applied to Output in HIGH State	
TRI-STATE Output	–0.5V to +5.5V
Current Applied to TTL	
Output in LOW State (Max)	Twice the Rated I_{OL} (mA)
ESD (Note 6)	≥2000V

Recommended Operating Conditions

Case Temperature (T_C)	
Military	–55˚C to +125˚C
ECL Supply Voltage (V_{EE})	–5.7V to –4.2V
TTL Supply Voltage (V_{TTL})	+4.5V to +5.5V

Note 5: Absolute maximum ratings are those values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 6: ESD testing conforms to MIL-STD-883, Method 3015.

Note 7: Either voltage limit or current limit is sufficient to protect inputs.

Military Version
TTL-to-ECL DC Electrical Characteristics

V_{EE} = –4.2V to –5.7V, V_{CC} = V_{CCA} = GND, T_C = –55˚C to +125˚C, V_{TTL} = +4.5V to +5.5V

Symbol	Parameter	Min	Max	Units	T_C	Conditions		Notes
V_{OH}	Output HIGH Voltage	–1025	–870	mV	0˚C to +125˚C	V_{IN} = V_{IH} (Max) or V_{IL} (Min)	Loading with 50Ω to –2.0V	(Notes 8, 9, 10)
		–1085	–870	mV	–55˚C			
V_{OL}	Output LOW Voltage	–1830	–1620	mV	0˚C to +125˚C			
		–1830	–1555	mV	–55˚C			
	Cutoff Voltage		–1950	mV	0˚C to +125˚C	OE or DIR Low		
			–1850	mV	–55˚C			
V_{OHC}	Output HIGH Voltage	–1035		mV	0˚C to +125˚C	V_{IN} = V_{IH} (Min) or V_{IL} (Max)	Loading with 50Ω0 to –2.0V	(Notes 8, 9, 10)
		–1085		mV	–55˚C			
V_{OLC}	Output LOW Voltage		–1610	mV	0˚C to +125˚C			
			–1555	mV	–55˚C			
V_{IH}	Input HIGH Voltage	2.0		V	–55˚C to +125˚C	Over V_{TTL}, V_{EE}, T_C Range		(Notes 8, 9, 10, 11)
V_{IL}	Input LOW Voltage		0.8	V	–55˚C to +125˚C	Over V_{TTL}, V_{EE}, T_C Range		(Notes 8, 9, 10, 11)
I_{IH}	Input HIGH Current		70	µA	–55˚C to 125˚C	V_{IN} = +2.7V		(Notes 8, 9, 10)
	Breakdown Test		1.0	mA	–55˚C to +125˚C	V_{IN} = +5.5V		
I_{IL}	Input LOW Current	–1.0		mA	–55˚C to +125˚C	V_{IN} = +0.5V		(Notes 8, 9, 10)
V_{FCD}	Input Clamp Diode Voltage	–1.2		V	–55˚C to +125˚ C	I_{IN} = –18 mA		(Notes 8, 9, 10)
I_{EE}	V_{EE} Supply Current				–55˚C to +125˚C	LE Low, OE and DIR High Inputs Open		(Notes 8, 9, 10)
		–165	–73	mA		V_{EE} = –4.2V to –4.8V		
		–175	–73			V_{EE} = –4.2V to –5.7V		

Military Version
ECL-to-TTL DC Electrical Characteristics

V_{EE} = −4.2V to −5.7V, V_{CC} = V_{CCA} = GND, T_C = −55°C to +125°C, C_L = 50 pF, V_{TTL} = +4.5V to + 5.5V

| Symbol	Parameter	Min	Max	Units	T_C	Conditions	Notes
V_{OH}	Output HIGH Voltage	2.5 2.4		mV	0°C to +125°C −55°C	I_{OH} = −1 mA, V_{TTL} = 4.50V	(Notes 8, 9, 10)
V_{OL}	Output LOW Voltage		0.5	mV	−55°C +125°C	I_{OL} = 24 mA, V_{TTL} = 4.50V	
V_{IH}	Input HIGH Voltage	−1165	−870	mV	−55°C +125°C	Guaranteed HIGH Signal for All Inputs	(Notes 8, 9, 10, 11)
V_{IL}	Input LOW Voltage	−1830	−1475	mV	−55°C to +125°C	Guaranteed LOW Signal for All Inputs	(Notes 8, 9, 10, 11)
I_{IH}	Input HIGH Current		350 500	µA	0°C to +125°C	V_{EE} = −5.7V V_{IN} = V_{IH} (Max)	(Notes 8, 9, 10)
I_{IL}	Input LOW Current	0.50		µA	−55°C to +125°C	V_{EE} = −4.2V V_{IN} = V_{IL} (Min)	(Notes 8, 9, 10)
I_{OZHT}	TRI-STATE Current Output High		70	µA	−55°C to +125°C	V_{OUT} = +2.7V	(Notes 8, 9, 10)
I_{OZLT}	TRI-STATE Current Output Low	−1.0		mA	−55°C to +125°C	V_{OUT} = +0.5V	(Notes 8, 9, 10)
I_{OS}	Output Short-Circuit CURRENT	−150	−60	mA	−55°C to +125°C	V_{OUT} = 0.0V, V_{TTL} = +5.5V	(Notes 8, 9, 10)
I_{TTL}	V_{TTL} Supply Current		75 50 70	mA mA mA	−55°C to +125°C	TTL Outputs Low TTL Output High TTL Output in TRI-STATE	(Notes 8, 9, 10)

Note 8: F100K 300 Series cold temperature testing is performed by temperature soaking (to guarantee junction temperature equals −55°C), then testing immediately without allowing for the junction temperature to stabilize due to heat dissipation after power-up. This provides "cold start" specs which can be considered a worst case condition at cold temperatures.

Note 9: Screen tested 100% on each device at −55°C, +25°C, and +125°C, Subgroups, 1, 2 3, 7, and 8.

Note 10: Sample tested (Method 5005, Table I) on each manufactured lot at −55°C, +25°C, and +125°C, Subgroups A1, 2, 3, 7, and 8.

Note 11: Guaranteed by applying specified input condition and testing V_{OH}/V_{OL}.

Military Version
TTL-to-ECL AC Electrical Characteristics

V_{EE} = −4.2V to −5.7V, V_{TTL} = +4.5V to +5.5V, V_{CC} = V_{CCA} = GND

Symbol	Parameter	T_C = −55°C		T_C = 25°C		T_C = +125°C		Units	Conditions	Notes
		Min	Max	Min	Max	Min	Max			
t_{PLH} t_{PHL}	T_N to E_n (Transparent)	0.8	3.4	1.1	3.6	0.8	3.7	ns ns	*Figures 1, 2*	(Notes 12, 13, 14)
t_{PLH} t_{PHL}	LE to E_n	1.2	3.8	1.4	3.7	1.1	3.8	ns ns	*Figures 1, 2*	
t_{PZH}	OE to E_n (Cutoff to HIGH)	0.8	3.6	1.5	4.0	2.0	5.2	ns	*Figures 1, 2*	(Notes 12, 13, 14)
t_{PHZ}	OE to E_n (HIGH to Cutoff)	1.5	4.6	1.6	4.2	1.6	4.3	ns	*Figures 1, 2*	
t_{PHZ}	DIR to E_n (HIGH to Cutoff)	1.6	4.7	1.6	4.3	1.7	4.3	ns	*Figures 1, 2*	
t_{set}	T_n to LE	2.5		2.0		2.5		ns	*Figures 1, 2*	(Note 15)
t_{hold}	T_n to LE	2.5		2.0		2.5		ns	*Figures 1, 2*	
$t_{pw}(H)$	Pulse Width LE	2.5		2.0		2.5		ns	*Figures 1, 2*	(Note 15)
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.4	2.3	0.5	2.1	0.4	2.4	ns	*Figures 1, 2*	(Note 15)

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Military Version
ECL-to-TTL AC Electrical Characteristics

$V_{EE} = -4.2V$ to $-5.7V$, $V_{TTL} = +4.5V$ to $+5.5V$, $V_{CC} = V_{CCA} = GND$, $C_L = 50$ pF

Symbol	Parameter	$T_C = -55°C$		$T_C = 25°C$		$T_C = +125°C$		Units	Conditions	Notes
		Min	Max	Min	Max	Min	Max			
t_{PLH}	E_n to T_n	2.1	6.0	2.0	5.6	2.2	6.3	ns	*Figures 1, 2*	(Notes 12, 13,
t_{PHL}	(Transparent)									14)
t_{PLH}	LE to T_n	3.1	7.0	3.1	6.5	3.3	7.5	ns	*Figures 3, 4*	
t_{PHL}										
t_{PZH}	OE to T_n	3.2	8.0	3.7	8.0	4.0	9.2	ns	*Figures 3, 4*	(Notes 12, 13,
t_{PZL}	(Enable Time)	3.6	8.0	4.0	8.5	4.3	9.6			14)
t_{PHZ}	OE to T_n	3.2	8.5	3.3	8.0	3.5	8.4	ns	*Figures 3, 5*	
t_{PLZ}	(Disable Time)	3.0	8.0	3.4	7.5	4.1	10.0			
t_{PHZ}	DIR to T_n	2.6	7.0	2.6	7.0	2.9	8.0	ns	*Figures 3, 6*	
t_{PLZ}	(Disable Time)	2.7	7.0	3.1	7.0	4.0	10.0			
t_{set}	E_n to LE	2.5		2.0		2.5		ns	*Figures 3, 4*	(Note 15)
t_{hold}	E_n to LE	3.0		2.5		3.0		ns	*Figures 3, 4*	
$t_{pw}(H)$	Pulse Width LE	2.5		2.0		5.0		ns	*Figures 3, 4*	(Note 15)

Note 12: F100K 300 Series cold temperature testing is performed by temperature soaking (to guarantee junction temperature equals –55°C), then testing immediately after power-up. This provides "cold start" specs which can be considered a worst case condition at cold temperatures.

Note 13: Screen tested 100% on each device at +25°C, temperature only, Subgroup A9.

Note 14: Sample tested (Method 5005, Table I) on each mfg. lot at +25°C, Subgroup A9, and at +125°C and –55°C temperatures, Subgroups A10 and A11.

Note 15: Not tested at +25°C, +125°C and –55°C temperature (design characterization data).

Test Circuitry (TTL-to-ECL)
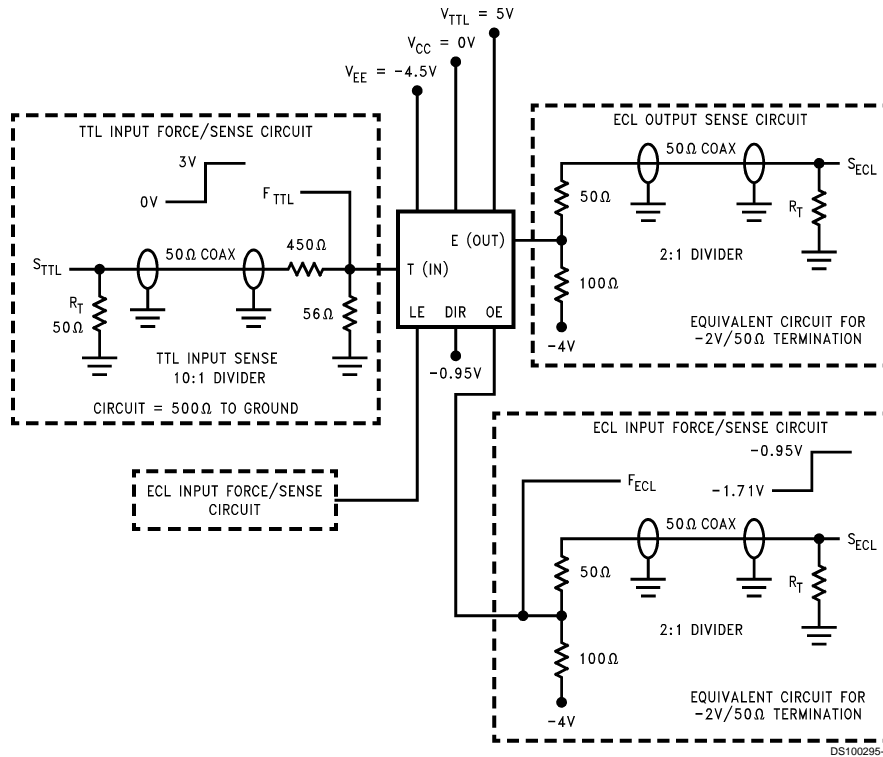
DS100295-7

Note 16: R$_t$ =50Ω termination. When an input or output is being monitored by a scope, R$_t$ is supplied by the scope's 50Ω resistance. When an input or output is not being monitored, an external 50Ω resistance must be applied to serve as R$_t$.

**Note 17:** TTL and ECL force signals are brought to the DUT via 50Ω coax lines.

Note 18: V$_{TTL}$ is decoupled to ground with 0.1 µF to ground, V$_{EE}$ is decoupled to ground with 0.01 µF and V$_{CC}$ is connected to ground.

Note 19: For ECL input pins, the equivelent force/sense circuitry is optional.

FIGURE 1. TTL-to-ECL AC Test Circuit

Switching Waveforms (TTL-to-ECL)
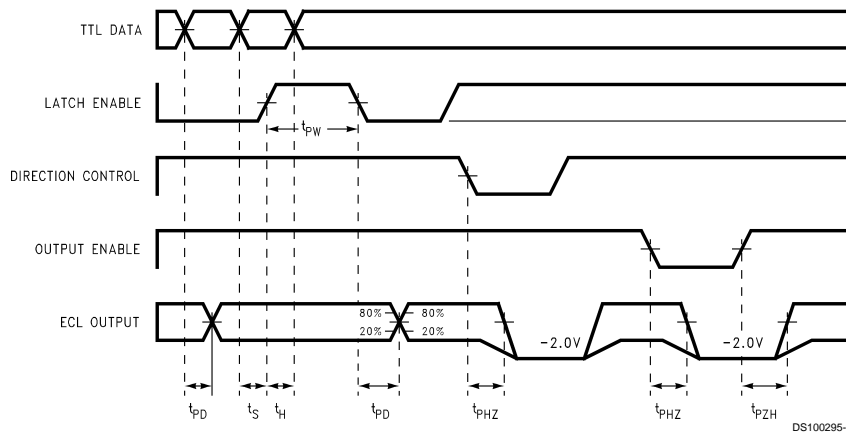
DS100295-9

FIGURE 2. TTL to ECL Transition — Propagation Delay and Transition Times

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Test Circuitry (ECL-to-TTL)
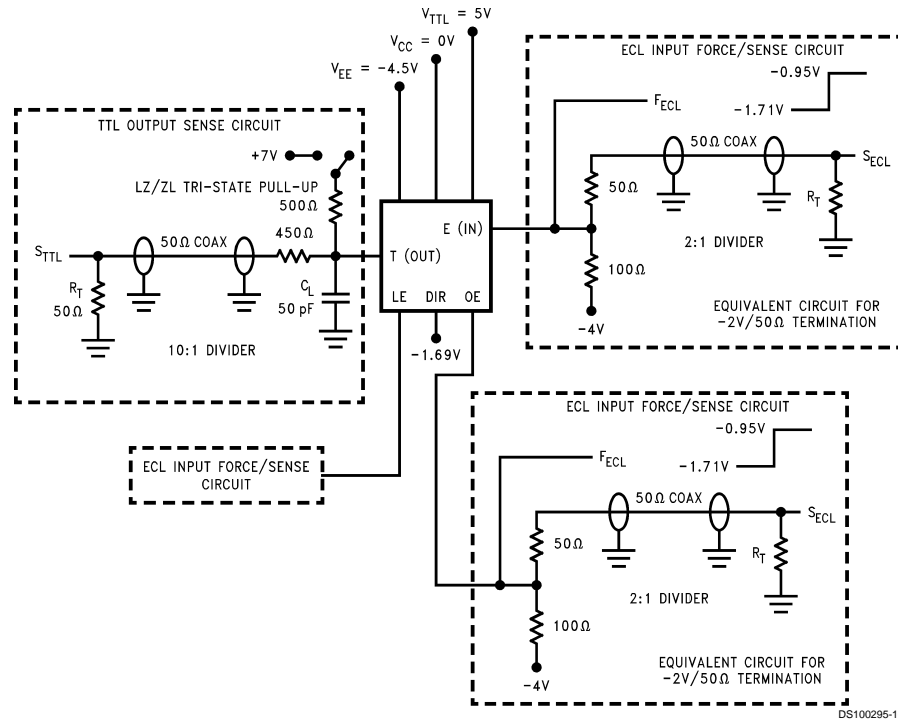
DS100295-10

Note 20: R_t =50Ω termination. When an input or output is being monitored by a scope, R_t is supplied by the scope's 50Ω resistance. When an input or output is not being monitored, an external 50Ω resistance must be applied to serve as R_t.

Note 21: The TTL TRI-STATE pull up switch is connected to +7V only for ZL and LZ tests.

Note 22: TTL and ECL force signals are brought to the DUT via 50Ω coax lines.

Note 23: V_{TTL} is decoupled to ground with 0.1 µF, V_{EE} is decoupled to ground with 0.01 µF and V_{CC} is connected to ground.

FIGURE 3. ECL-to-TTL AC Test Circuit

Switching Waveforms (ECL-to-TTL)
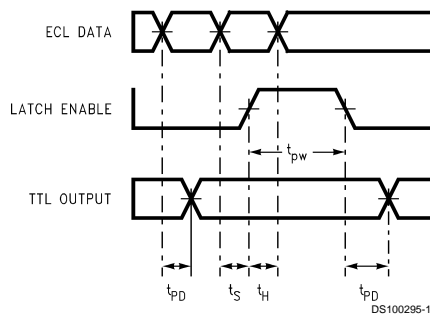
DS100295-11

Note 24: DIR is LOW, and OE is HIGH

FIGURE 4. ECL-to-TTL Transition — Propagation Delay and Transition Times

Switching Waveforms (ECL-to-TTL) (Continued)
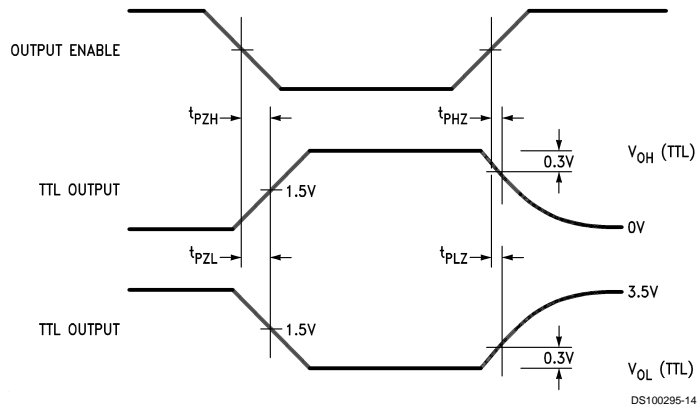
Note 25: DIR is LOW, LE is HIGH

FIGURE 5. ECL-to-TTL Transition, OE to TTL Output, Enable and Disable Times
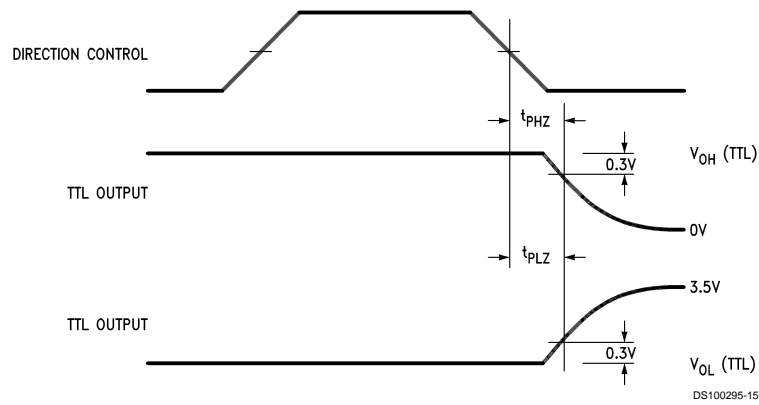
Note 26: OE is HIGH, LE is HIGH

FIGURE 6. ECL-to-TTL Transition, DIR to TTL Output, Disable Time

Applications
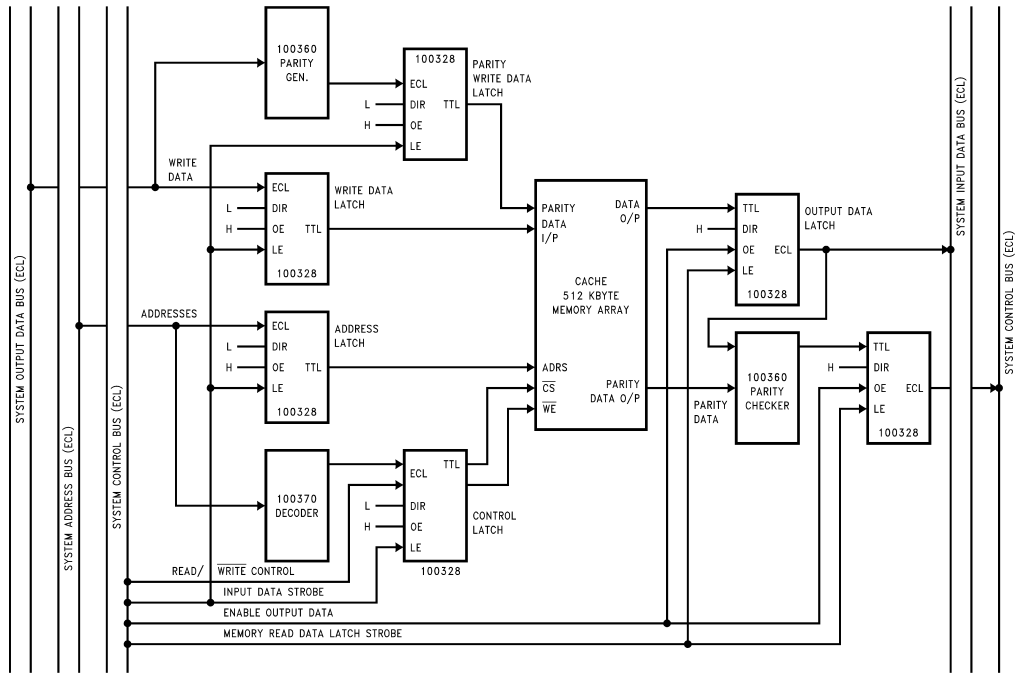
DS100295-12

FIGURE 7. Applications Diagram — MOS/TTL SRAM Interface Using 100328 ECL–TTL Latched Translator

Ordering Information

The device number is used to form part of a simplified purchasing code where A package type and temperature range are defined as follows:

100328　D　C　QB

Device Type (Basic)

Package Code
　D = Ceramic DIP
　F = Quad Cerpak
　P = Plastic DIP
　Q = Plastic Leaded Chip Carrier (PCC)
　S = Small Outline (SOIC)

Special Variation
　QB = Military grade device with
　　　　environmental and burn-in
　　　　processing

Temperature Range
　C = Commercial (0°C to +85°C)
　 I = Industrial (−40°C to +85°C)
　　　 (PCC Only)
　M = Military (−55°C to +125°C)
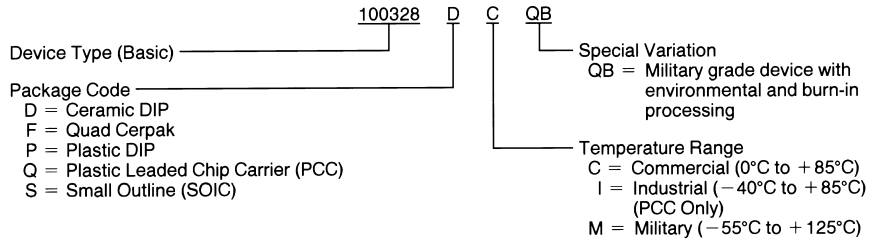
DS100295-16

Physical Dimensions inches (millimeters) unless otherwise noted
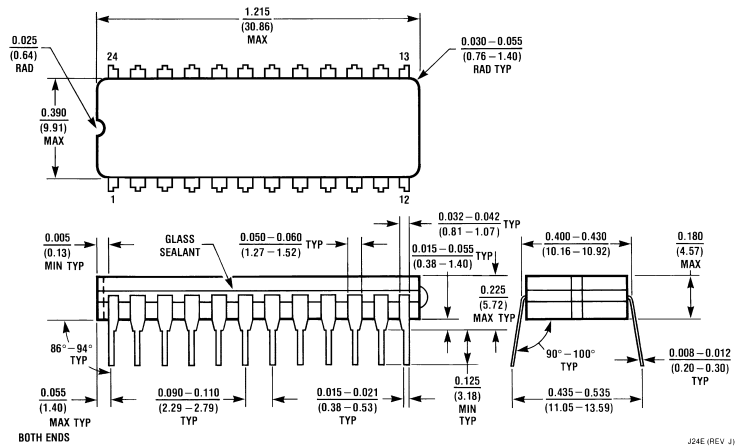
24-Lead Ceramic Dual-In-Line Package (0.400" Wide) (D)
NS Package Number J24E
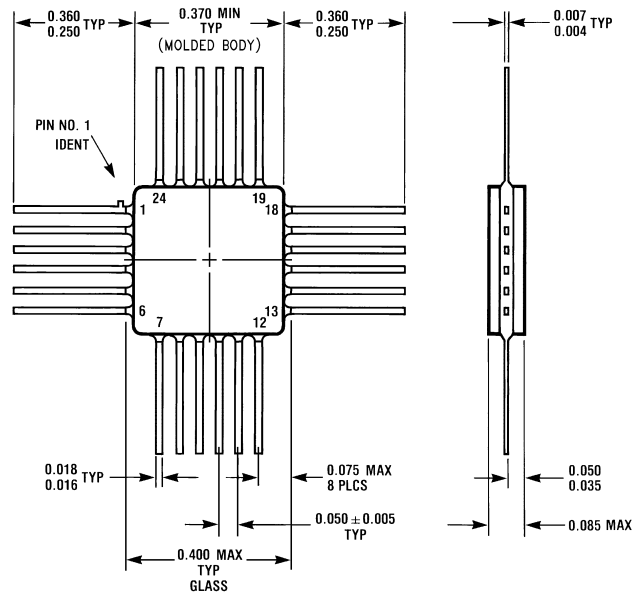
24-Lead Quad Cerpak (F)
NS Package Number W24B

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![×]
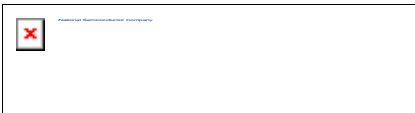
100328   Low Power ECL/TTL Bi-Directional Translator with Latch

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
The 100328 is designed with FAST TTL output buffers, featuring optimal DC drive and capable of quickly charging and discharging highly capacitive loads. All inputs have 50 k Ohm pull-down resistors.

Features

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- TRI-STATE outputs
- Voltage compensated operating range = -4.2V to -5.7V
- Available to MIL-STD-883

Datasheet

Title	Size (in Kbytes)	Date	View Online	Download	Receive via Email
100328 Low Power Octal ECL/TTL Bi-Directional Translator with Latch	263 Kbytes	2-Sep-98	View Online	Download	Receive via Email
100328 Mil-Aero Datasheet MN100328-X	62 Kbytes		View Online	Download	Receive via Email

Please use Adobe Acrobat to view PDF file(s).
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Package Availability, Models, Samples & Pricing

Part Number	Package		Status	Models		Samples & Electronic Orders	Budgetary Pricing		Std Pack Size	
	Type	# pins		SPICE	IBIS		Quantity	$US each		
100328DMQB	Cerdip	24	Full production	N/A	N/A	.	50+	$34.6000	tube of 15	[lo... 100...
100328FMQB	Cerquad	24	Full production	N/A	N/A	.	50+	$39.0000	tube of 14	[log...
100328FC	Cerquad	24	Full production	N/A	N/A	.			tube of N/A	[l...
100328 MW8	wafer		Full production	N/A	N/A	.			N/A	

Application Notes

Title	Size (in Kbytes)	Date	View Online	Download	Receive via Email
AN-1123: Application Note 1123 Sorting Out Backplane Driver Alphabet Soup	208 Kbytes	6-Apr-99	View Online	Download	Receive via Email

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